74AUP1G373

Low-power D-type transparent latch; 3-state

Rev. 9 — 20 January 2022

Product data sheet

1. General description

The 74AUP1G373 is a single D-type transparent latch; 3-state. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V. This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- CMOS low power dissipation
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- · Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8C (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AUP1G373GW	-40 °C to +125 °C	TSSOP6	plastic thin shrink small outline package; 6 leads; body width 1.25 mm	SOT363-2
74AUP1G373GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886
74AUP1G373GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115
74AUP1G373GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202



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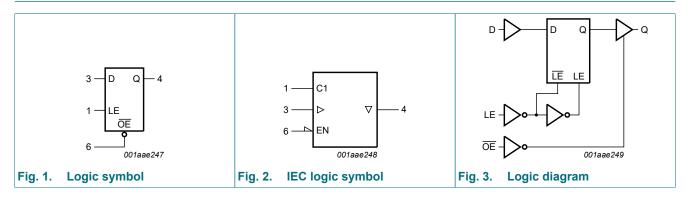
4. Marking

Table 2. Marking

Type number	Marking code [1]
74AUP1G373GW	aW
74AUP1G373GM	aW
74AUP1G373GN	aW
74AUP1G373GS	aW

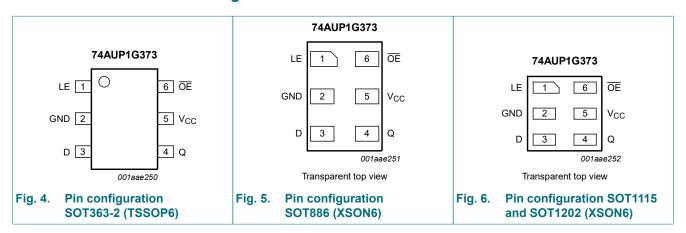
^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1. Pinning



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6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
LE	1	latch enable input (active HIGH)
GND	2	ground (0 V)
D	3	data input
Q	4	latch output
V _{CC}	5	supply voltage
ŌĒ	6	output enable input (active LOW)

7. Functional description

Table 4. Function table

H = HIGH voltage level; h = HIGH voltage level one setup time prior to the HIGH-to-LOW LE transition;

L = LOW voltage level; I = LOW voltage level one setup time prior to the HIGH-to-LOW LE transition;

X = Don't care; Z = high-impedance OFF-state.

Operating modes	Input		Internal latch	Output	
	OE	LE	D		Q
Enable and read register (transparent mode)	L	Н	L	L	L
	L	Н	Н	Н	Н
Latch and read register	L	L	I	L	L
	L	L	h	Н	Н
Latch register and disable outputs	Н	Х	Х	X	Z

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
Io	output current	$V_O = 0 \text{ V to } V_{CC}$	-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}$ [2]	-	250	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SOT886 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 $^{\circ}\text{C}.$

For SOT1115 (XSON6) package: P_{tot} derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

^[2] For SOT363-2 (TSSOP6) package: P_{tot} derates linearly with 3.7 mW/K above 83 °C.

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9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	-	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	25 °C					
V _{IH}	HIGH-level input	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}		V	
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-		V
V _{IL}	LOW-level input	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
	voltage	V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-		V
		V _{CC} = 3.0 V to 3.6 V	-	-		V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	0.70 × V _{CC}	V	
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-		V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-		V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-		V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-		V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-		V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	$I_O = 20 \mu A; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	- 0.30 × V _{CC} 0.35 × V _{CC} 0.35 × V _{CC} 0.7 0.9	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-		V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.35 × V _{CC} 0.7 0.9 0.1 0.3 × V _{CC} 0.31 0.31 0.44 0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-		V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-		V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OZ}	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.1	μΑ
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0 \text{ V}$ to 3.6 V; $V_{CC} = 0 \text{ V}$	-	-	±0.2	μΑ
Δl _{OFF}	additional power-off leakage current	V_{I} or $V_{O} = 0 \text{ V}$ to 3.6 V; $V_{CC} = 0 \text{ V}$ to 0.2 V	-	-	±0.2	μΑ
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μΑ
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	40	μΑ
Cı	input capacitance	V_{CC} = 0 V to 3.6 V; V_I = GND or V_{CC}	-	8.0	-	pF
Co	output capacitance	output enabled; V _O = GND; V _{CC} = 0 V	-	1.7	-	pF
		output disabled; V_{CC} = 0 V to 3.6 V; V_{O} = GND or V_{CC}	-	1.5	-	pF
T _{amb} = -4	40 °C to +85 °C				<u> </u>	•
V _{IH}	HIGH-level input	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
	voltage	V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	$I_O = 20 \mu A; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
l _l	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.5	μΑ
l _{OZ}	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.5	μΑ
l _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.5	μΑ
Δl _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.6	μA
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.9	μΑ
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	50	μA
T _{amb} = -4	40 °C to +125 °C					
V _{IH}	HIGH-level input	V _{CC} = 0.8 V	0.75 × V _{CC}	-	-	V
	voltage	V _{CC} = 0.9 V to 1.95 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	- ±0.5 μ/ - ±0.5 μ/ - ±0.5 μ/ - ±0.6 μ/ 50 μ/ 50 μ/ 7	V	
		V _{CC} = 3.0 V to 3.6 V	2.0	- ±0.6	V	
V _{IL}	LOW-level input	V _{CC} = 0.8 V	-	-	0.25 × V _{CC}	V
,	voltage	V _{CC} = 0.9 V to 1.95 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V			0.9	V
V _{OH}	V _{OH} HIGH-level output V _I = V _{IH} o	$V_I = V_{IH}$ or V_{IL}				
	voltage	I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		ent V _{CC} = 0 V to 3.6 V	-	V		
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _I	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μA
I _{OZ}	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.75	μA
I _{OFF}	power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.75	μA
Δl _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.75	μA
I _{CC}	supply current	V_I = GND or V_{CC} ; I_O = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	1.4	μΑ
ΔI _{CC}	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	75	μA

^[1] One input at V_{CC} - 0.6 V, other input at V_{CC} or GND.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 11.

Symbol	Parameter	Conditions		25 °C			°C to 5 °C		°C to 5 °C	Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
$C_L = 5 p$	F									
t _{pd}	propagation	D to Q; see <u>Fig. 7</u> [2]								
	delay	V _{CC} = 0.8 V	-	21.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.8	6.6	13.5	2.6	13.8	2.6	15.2	ns
		V _{CC} = 1.4 V to 1.6 V	2.4	4.6	7.8	2.1	8.3	2.1	9.1	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.7	6.2	1.6	6.7	1.6	7.3	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	2.9	4.1	1.5	4.5	1.5	4.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.5	2.5	3.5	1.2	4.0	1.2	4.5	ns
		LE to Q; see Fig. 8 [2]								
		V _{CC} = 0.8 V	-	20.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.7	6.2	13.6	2.5	14.0	2.5	15.4	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	4.4	7.6	2.0	8.5	2.0	9.3	ns
		V _{CC} = 1.65 V to 1.95 V	1.8	3.5	5.8	1.5	6.7	1.5	7.3	ns
		V _{CC} = 2.3 V to 2.7 V	1.5	2.6	4.0	1.3	4.4	1.3	4.8	ns
		V _{CC} = 3.0 V to 3.6 V	1.3	2.2	3.3	1.1	3.8	1.1	4.2	ns
t _{en}	enable time	OE to Q; see <u>Fig. 10</u> [3]								
		V _{CC} = 0.8 V	-	17.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	5.1	9.2	3.0	9.2	3.0	10.1	ns
		V _{CC} = 1.4 V to 1.6 V	2.6	3.8	5.8	2.4	6.1	2.4	6.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.2	3.3	4.8	2.0	5.0	2.0	5.5	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	2.7	3.8	1.8	4.0	1.8	4.4	ns
		V _{CC} = 3.0 V to 3.6 V	1.9	2.5	3.4	1.8	3.6	1.8	4.0	ns

Symbol	Parameter	Conditions		25 °C			°C to 5 °C		°C to 5 °C	Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
t _{dis}	disable time	OE to Q; see <u>Fig. 10</u> [4]								
		V _{CC} = 0.8 V	-	9.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.9	4.2	7.5	2.8	7.9	2.8	8.7	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	3.2	4.9	2.1	5.3	2.1	5.8	ns
		V _{CC} = 1.65 V to 1.95 V	2.2	3.0	4.4	2.1	4.9	2.1	5.4	ns
		V _{CC} = 2.3 V to 2.7 V	1.6	2.2	3.1	1.5	3.4	1.5	3.7	ns
		V _{CC} = 3.0 V to 3.6 V	1.9	2.6	3.3	1.8	3.6	1.8	4.0	ns
C _L = 10	pF						'		,	
t _{pd}	propagation	D to Q; see <u>Fig. 7</u> [2]								
	delay	V _{CC} = 0.8 V	-	24.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.0	7.5	15.3	2.7	15.9	2.7	17.4	ns
		V _{CC} = 1.4 V to 1.6 V	2.6	5.3	9.0	2.2	9.4	2.2	10.3	ns
		V _{CC} = 1.65 V to 1.95 V	2.5	4.3	6.9	2.1	7.3	2.1	8.0	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	3.5	4.8	1.8	5.3	1.8	5.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.8	3.1	4.2	1.7	4.6	1.7	5.1	ns
		LE to Q; see Fig. 8 [2]								
		V _{CC} = 0.8 V	-	23.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.9	7.1	15.4	2.7	16.1	2.7	17.7	ns
		V _{CC} = 1.4 V to 1.6 V	2.5	5.0	8.8	2.1	9.5	2.1	10.4	ns
		V _{CC} = 1.65 V to 1.95 V	2.3	4.1	6.6	2.0	7.3	2.0	8.1	ns
		V _{CC} = 2.3 V to 2.7 V	1.9	3.1	4.7	1.6	5.2	1.6	5.8	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	2.8	4.0	1.4	4.4	1.4	4.9	ns
t _{en}	enable time	OE to Q; see <u>Fig. 10</u> [3]								
		V _{CC} = 0.8 V	-	21.2	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.7	6.0	10.6	3.4	10.6	3.4	11.7	ns
		V _{CC} = 1.4 V to 1.6 V	3.1	4.5	6.7	2.8	7.0	2.8	7.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.7	3.9	5.5	2.5	5.8	2.5	6.4	ns
		V _{CC} = 2.3 V to 2.7 V	2.4	3.3	4.5	2.2	4.7	2.2	5.2	ns
		V _{CC} = 3.0 V to 3.6 V	2.3	3.1	4.1	2.2	4.3	2.2	4.7	ns
t _{dis}	disable time	OE to Q; see <u>Fig. 10</u> [4]								
		V _{CC} = 0.8 V	-	11.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.9	5.3	8.7	3.8	9.2	3.8	10.1	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	4.1	5.8	2.9	6.2	2.9	6.8	ns
		V _{CC} = 1.65 V to 1.95 V	3.2	4.2	5.7	3.1	6.0	3.1	6.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.3	3.0	4.0	2.2	4.3	2.2	4.7	ns
		V _{CC} = 3.0 V to 3.6 V	3.0	3.8	4.7	2.9	5.0	2.9	5.5	ns

Symbol	Parameter	arameter Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ [1]	Max	x Min Max		Min	Max	
C _L = 15	pF									
t _{pd}	propagation	D to Q; see <u>Fig. 7</u> [2]								
	delay	V _{CC} = 0.8 V	-	27.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.5	8.3	16.9	3.2	17.5	3.2	19.2	ns
		V _{CC} = 1.4 V to 1.6 V	3.1	5.9	9.6	2.7	10.5	2.7	11.6	ns
		V _{CC} = 1.65 V to 1.95 V	2.6	4.8	7.6	2.2	8.5	2.2	9.3	ns
		V _{CC} = 2.3 V to 2.7 V	2.5	3.9	5.5	2.2	5.9	2.2	6.5	ns
		V _{CC} = 3.0 V to 3.6 V	2.2	3.6	4.9	1.8	5.5	1.8	6.0	ns
		LE to Q; see Fig. 8 [2]								
		V _{CC} = 0.8 V	-	26.1	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.3	7.9	17.3	3.0	18.0	3.0	19.8	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.6	9.7	2.5	10.7	2.5	11.8	ns
		V _{CC} = 1.65 V to 1.95 V	2.5	4.6	7.4	2.2	8.3	2.2	9.1	ns
		V _{CC} = 2.3 V to 2.7 V	2.3	3.6	5.3	2.0	5.9	2.0	6.4	ns
		V _{CC} = 3.0 V to 3.6 V	2.1	3.2	4.6	1.8	5.1	1.8	5.6	ns
t _{en}	enable time	OE to Q; see <u>Fig. 10</u> [3]								
		V _{CC} = 0.8 V	-	24.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.1	6.8	12.1	3.8	12.1	3.8	13.3	ns
		V _{CC} = 1.4 V to 1.6 V	3.5	5.1	7.5	3.2	7.9	3.2	8.7	ns
		V _{CC} = 1.65 V to 1.95 V	3.1	4.4	6.1	2.8	6.5	2.8	7.2	ns
		V _{CC} = 2.3 V to 2.7 V	2.8	3.7	5.0	2.5	5.3	2.5	5.8	ns
		V _{CC} = 3.0 V to 3.6 V	2.6	3.5	4.7	2.5	4.9	2.5	5.4	ns
t _{dis}	disable time	OE to Q; see <u>Fig. 10</u> [4]								
		V _{CC} = 0.8 V	-	13.1	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.9	6.5	9.8	4.8	10.4	4.8	11.4	ns
		V _{CC} = 1.4 V to 1.6 V	3.9	5.0	6.8	3.8	7.3	3.8	8.0	ns
		V _{CC} = 1.65 V to 1.95 V	4.2	5.3	6.9	4.1	7.3	4.1	8.0	ns
		V _{CC} = 2.3 V to 2.7 V	3.0	3.8	4.8	2.9	5.1	2.9	5.6	ns
		V _{CC} = 3.0 V to 3.6 V	4.1	5.0	6.1	4.0	6.4	4.0	7.0	ns

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
C _L = 30	pF									
t _{pd}	propagation	D to Q; see <u>Fig. 7</u> [2]								
	delay	V _{CC} = 0.8 V	-	35.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.0	10.6	22.1	3.7	23.3	3.7	25.6	ns
		V _{CC} = 1.4 V to 1.6 V	3.6	7.5	12.3	3.5	13.6	3.5	15.0	ns
		V _{CC} = 1.65 V to 1.95 V	3.5	6.2	9.5	3.2	10.5	3.2	11.5	ns
		V _{CC} = 2.3 V to 2.7 V	3.3	5.1	6.9	2.9	7.6	2.9	8.3	ns
		V _{CC} = 3.0 V to 3.6 V	3.0	4.7	6.4	2.9	7.2	2.9	7.9	ns
		LE to Q; see Fig. 8 [2]								
		V _{CC} = 0.8 V	-	34.8	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.9	10.2	22.2	3.7	23.5	3.7	25.9	ns
		V _{CC} = 1.4 V to 1.6 V	3.5	7.2	12.4	3.4	13.7	3.4	15.1	ns
		V _{CC} = 1.65 V to 1.95 V	3.3	5.9	9.5	3.0	10.5	3.0	11.6	ns
		V _{CC} = 2.3 V to 2.7 V	3.1	4.8	6.8	2.7	7.5	2.7	8.2	ns
		V _{CC} = 3.0 V to 3.6 V	2.9	4.4	6.1	2.6	7.0	2.6	7.7	ns
t _{en}	enable time	OE to Q; see <u>Fig. 10</u> [3]								
		V _{CC} = 0.8 V	-	34.5	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	5.5	9.1	16.2	4.9	16.2	4.9	17.8	ns
		V _{CC} = 1.4 V to 1.6 V	4.6	6.7	9.9	4.2	10.5	4.2	11.6	ns
		V _{CC} = 1.65 V to 1.95 V	4.2	5.7	7.9	3.7	8.6	3.7	9.5	ns
		V _{CC} = 2.3 V to 2.7 V	3.6	4.9	6.4	3.4	6.9	3.4	7.6	ns
		V _{CC} = 3.0 V to 3.6 V	3.4	4.7	6.1	3.3	6.5	3.3	7.2	ns
t _{dis}	disable time	OE to Q; see <u>Fig. 10</u> [4]								
		V _{CC} = 0.8 V	-	19.2	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	8.0	9.9	13.7	7.9	14.5	7.9	16.0	ns
		V _{CC} = 1.4 V to 1.6 V	6.3	7.7	9.7	6.2	10.5	6.2	11.6	ns
		V _{CC} = 1.65 V to 1.95 V	7.3	8.7	10.6	7.2	11.3	7.2	12.4	ns
		V _{CC} = 2.3 V to 2.7 V	5.2	6.2	7.5	5.1	7.8	5.1	8.6	ns
		V _{CC} = 3.0 V to 3.6 V	7.5	8.8	10.2	7.4	10.5	7.4	11.6	ns
C _L = 5 p	F, 10 pF, 15 p	F and 30 pF								
t _W	pulse width	LE HIGH; see Fig. 8								Т
		V _{CC} = 0.8 V	-	4.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	0.7	-	2.1	-	2.1	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	0.5	-	1.3	-	1.3	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	0.4	-	1.0	-	1.0	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	0.3	-	0.8	-	0.8	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	0.2	-	0.8	-	0.8	-	ns

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Symbol	Parameter	Conditions		25 °C			°C to			Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
t _{su(H)}	set-up time	D to LE; see Fig. 9								
	HIGH	V _{CC} = 0.8 V	-	4.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	0.9	-	2.2	-	2.2	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	0.6	-	1.4	-	1.4	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	0.4	-	1.0	-	1.0	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	0	-	0.6	-	0.6	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	-0.1	-	0.4	-	0.4	-	ns
t _{su(L)}	set-up time	D to LE; see Fig. 9								
	LOW	V _{CC} = 0.8 V	-	4.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	1.2	-	2.7	-	2.7	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	0.7	-	1.5	-	1.5	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	0.6	-	1.2	-	1.2	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	0.4	-	0.9	-	0.9	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	0.3	-	0.7	-	0.7	-	ns
t _h	hold time	D to LE HIGH or LOW; see Fig. 9								
		V _{CC} = 0.8 V	-	-4.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	-	-0.9	-	-0.1	-	-0.1	-	ns
		V _{CC} = 1.4 V to 1.6 V	-	-0.6	-	-0.1	-	-0.1	-	ns
		V _{CC} = 1.65 V to 1.95 V	-	-0.4	-	0	-	0	-	ns
		V _{CC} = 2.3 V to 2.7 V	-	-0.2	-	0.2	-	0.2	-	ns
		V _{CC} = 3.0 V to 3.6 V	-	-0.1	-	0.3	-	0.3	-	ns
C _{PD}	power dissipation	f_i = 1 MHz; V_I = GND to V_{CC} ; [5][6] output enabled								
	capacitance	V _{CC} = 0.8 V	-	2.0	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.0	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	2.0	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	2.1	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	2.4	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	2.8	-	-	-	-	-	pF

- All typical values are measured at nominal V_{CC}.
- t_{pd} is the same as t_{PLH} and t_{PHL} . [2]
- t_{en} is the same as t_{PZH} and t_{PZL}.
- ten is the same as tpHz and tpLz.
 td_{is} is the same as tpHz and tpLz.
 All specified values are the average typical values over all stated loads.
 C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
 P_D = C_{PD} × V_{CC}² × f_i × N + Σ(C_L × V_{CC}² × f_o) where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

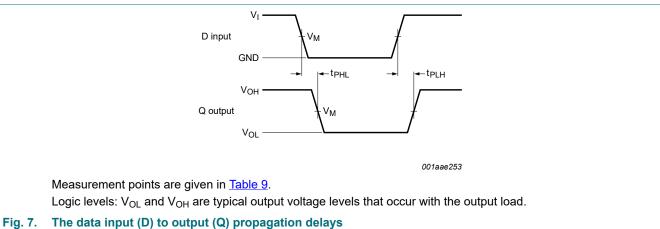
C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V; $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs;

N = number of inputs switching.

Low-power D-type transparent latch; 3-state

11.1. Waveforms and test circuit





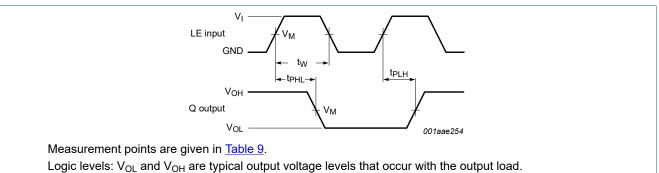


Fig. 8. The latch enable input (LE) to output (Q) propagation delays, the latch enable input (LE) pulse width

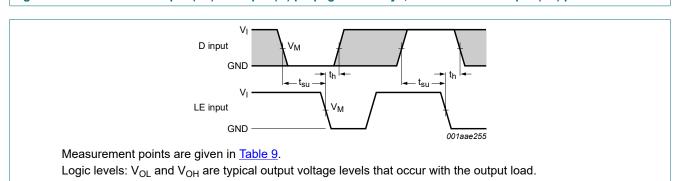
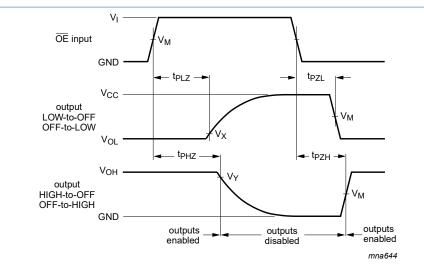


Fig. 9. Data set-up and hold times for the D input to the LE input

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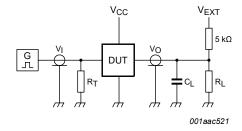
Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 10. Turn-on and turn-off times

Table 9. Measurement points

Supply voltage	Input	Input			Output			
V _{CC}	V _M	VI	$t_r = t_f$	V _M	V _X	V _Y		
0.8 V to 1.6 V	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.1 V	V _{OH} - 0.1 V		
1.65 V to 2.7 V	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.15 V	V _{OH} - 0.15 V		
3.0 V to 3.6 V	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}	V _{OL} + 0.3 V	V _{OH} - 0.3 V		



Test data is given in Table 10.

Definitions for test circuit:

R_I = Load resistance;

C_L = Load capacitance including jig and probe capacitance;

 R_T = Termination resistance should be equal to the output impedance Z_0 of the pulse generator;

V_{EXT} = External voltage for measuring switching times.

Fig. 11. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Load	V _{EXT}			
V _{CC}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V _{CC}

[1] For measuring enable and disable times R_L = 5 k Ω .

For measuring propagation delays, setup and hold times and pulse width R_L = 1 $\mbox{M}\Omega.$

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12. Package outline

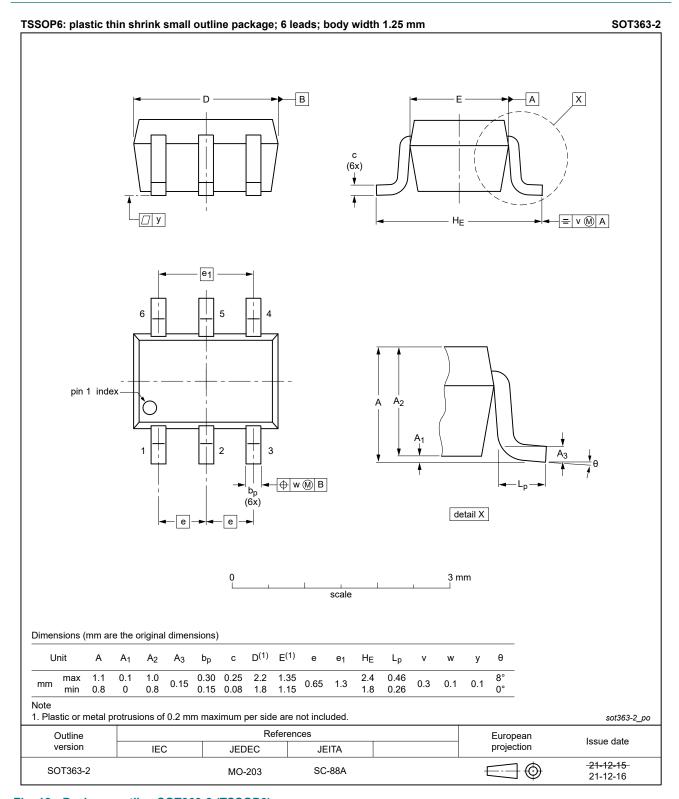


Fig. 12. Package outline SOT363-2 (TSSOP6)

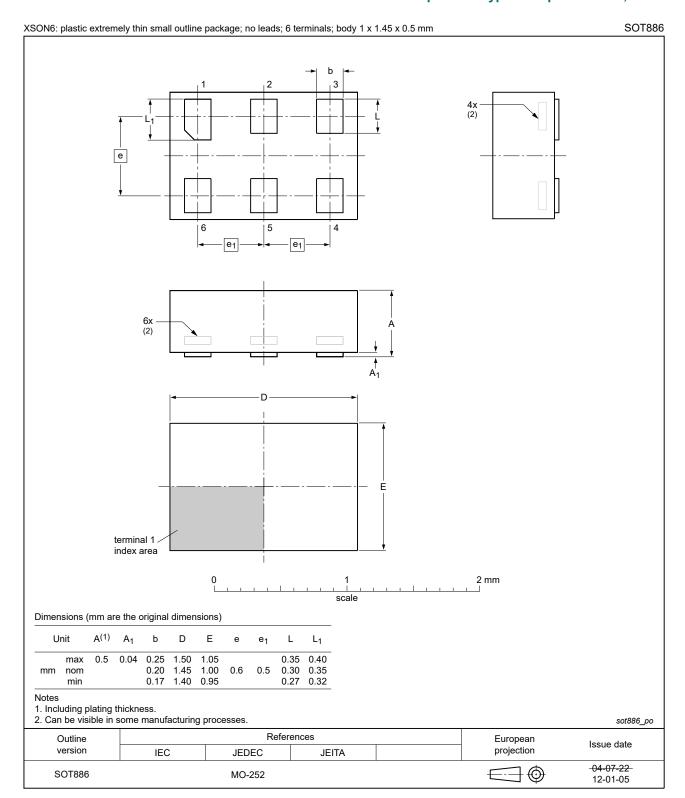


Fig. 13. Package outline SOT886 (XSON6)

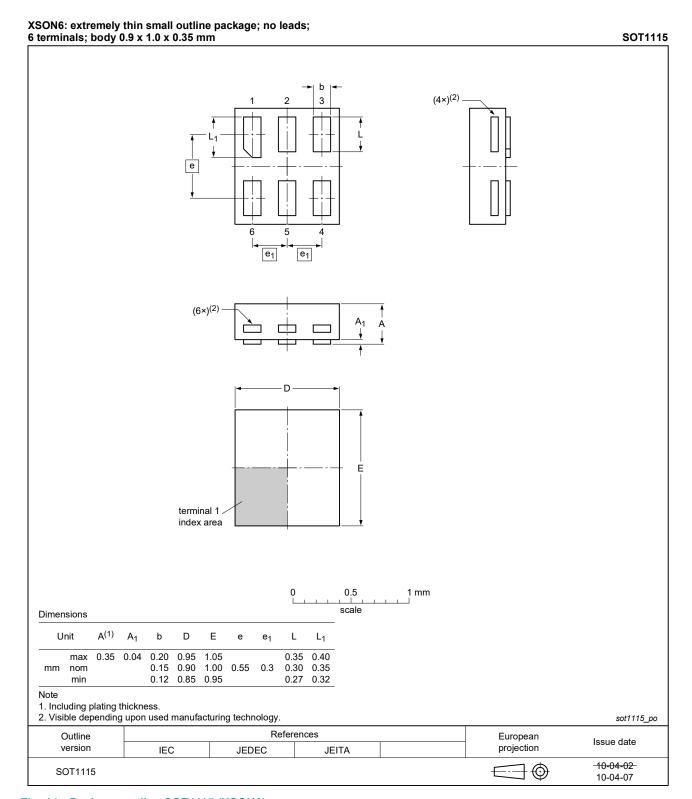


Fig. 14. Package outline SOT1115 (XSON6)

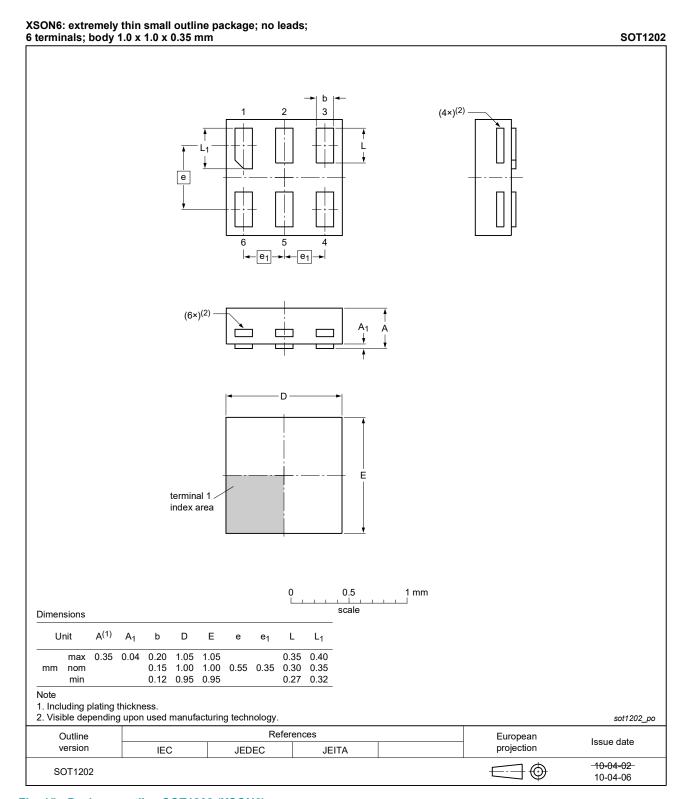


Fig. 15. Package outline SOT1202 (XSON6)

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13. Abbreviations

Table 11. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74AUP1G373 v.9	20220120	Product data sheet	-	74AUP1G373 v.8		
 Modifications: Section 1 and Section 2 updated. Package SOT363 (SC-88) changed to SOT363-2 (TSSOP6). 						
74AUP1G373 v.8	20210519	Product data sheet	-	74AUP1G373 v.7		
Modifications:	 Type number 74AUP1G373GF (SOT891 / XSON6) removed. Section 1 and Section 2 updated. 					
74AUP1G373 v.7	20200327	Product data sheet	-	74AUP1G373 v.6		
Modifications: 74AUP1G373 v.6	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Table 5: Derating values for P_{tot} total power dissipation updated. 20120704 Product data sheet Table 5: Product data sheet Product data sheet 					
Modifications:		tline drawing of SOT886 (ig 13) modified	7 1.01 1.00 1.00		
74AUP1G373 v.5 Modifications:	20111125 • Legal pages	Product data sheet	-	74AUP1G373 v.4		
74AUP1G373 v.4	20100715	Product data sheet	-	74AUP1G373 v.3		
74AUP1G373 v.3	20080109	Product data sheet	-	74AUP1G373 v.2		
74AUP1G373 v.2	20070720	Product data sheet	-	74AUP1G373 v.1		
74AUP1G373 v.1	20061129	Product data sheet	-	-		

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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Low-power D-type transparent latch; 3-state

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